

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

Group Art Unit: 2814 2 1103

UEMURA et al.

Appln. No.: 08/866,129

Filed: May 30, 1997

DEVICES RELATED TO ELECTRODE PADS FOR P-TYPE GROUP III NITRIDE For:

COMPOUND SEMICONDUCTORS (AS AMENDED)

November 8, 2002

AMENDMENT

Hon. Commissioner of Patents Washington, D.C. 20231

Sir:

In response to the Office Action mailed January 18, 2002 (a Request for Continued Examination and Request for Three Months Suspension of Prosecution having been filed on July 10, 2002), please amend the above-identified application as follows

IN THE CLAIMS:

Please cancel claims 29 and 31 without prejudice or disclaimer.

Please enter the following amended claim.

12. (Four Times Amended) A light-emitting semiconductor device having a Group III nitride compound semiconductor comprising:

a surface layer made of p-type semiconductor;

a multi-layered electrode layer comprising a first electrode layer formed on said surface layer and a second electrode layer formed on said first electrode layer;

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